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The Hall number across a van Hove singularity ILYA ESTERLIS, AKASH MAHARAJ, Stanford University, YI ZHANG, Cornell University, BRAD RAMSHAW, Los Alamos National Laboratory, STEVEN KIVELSON, Stanford University — In the context of the relaxation time approximation to Boltzmann transport theory, we examine the behavior of the Hall number,  $n_H$ , of a metal in the neighborhood of a Lifshitz transition from a closed Fermi surface to open sheets. A non-analytic dependence of  $n_H$  on the electron density is universal in the high field limit, but at low fields the behavior is non-singular and non-universal. We find, however, that for suitable choice of band-parameters a singular change in the low-field  $n_H$  occurs near a continuous nematic-order-driven Lifshitz transition. This behavior of  $n_H$  is similar to that seen in recent experiments in the high temperature superconductor YBa<sub>2</sub>Cu<sub>3</sub>O<sub>7-x</sub>, where a sharp drop in  $n_H$  occurs below optimal doping.

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